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## **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

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December 2005

### FDS8449

FAIRCHILD SEMICONDUCTOR

### 40V N-Channel PowerTrench<sup>®</sup> MOSFET

#### **General Description**

These N-Channel MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

#### Application

- Inverter
- Power Supplies

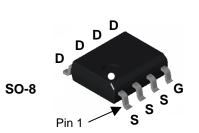
#### Features

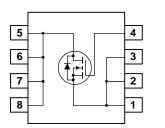
• 7.6 A, 40V  $R_{DS(on)} = 29m\Omega @ V_{GS} = 10V$ 

 $R_{DS(on)} = 36m\Omega @ V_{GS} = 4.5V$ 

- High power handling capability in a widely used surface mount package
- RoHS compliant







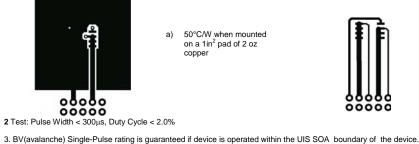
#### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

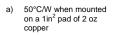
Symbol	Parameter			Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage			40	V
V <sub>GSS</sub>	Gate-Source Voltage			±20	V
I <sub>D</sub>	Drain Currer	nt – Continuous	(Note 1a)	7.6	А
– Pulsed				50	
PD	Power Dissi	pation for Single Operation	(Note 1a)	2.5	W
			(Note 1b)	1	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	
Therma R <sub>0JA</sub>	Thermal Res	eristics	ent (Note 1a)	50	°C/W
R <sub>eJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1b)		ent (Note 1b)	125	
R <sub>eJC</sub>	Thermal Resistance, Junction-to-Case (Note 1)			25	
Packag	e Marking	g and Ordering Ir	nformation		·
Device Marking		Device	Reel Size	Tape width	Quantity
	FDS8449 FDS8449				

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	urce Avalanche Ratings (Note	e 3)				
AS	Drain-Source Avalanche Energy	$V_{DD} = 40 \text{ V},  I_D = 7.3 \text{ A}, \text{ L} = 1 \text{ mH}$			27	mJ
AS	Drain-Source Avalanche Current			7.3		Α
Off Char	acteristics	•	•			
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_{D} = 250 \mu A$	40			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		34		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 32 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			1	μΑ
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS}=\pm 20~V, ~~V_{DS}=0~V$			±100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1	1.9	3	V
$\Delta V_{GS(th)}$ $\Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		-5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \ V, & I_D = 7.6 \ A \\ V_{GS} = 4.5 \ V, & I_D = 6.8 \ A \\ V_{GS} = 10 \ V, \ I_D = 7.6 \ A, \ T_J = 125^\circ C \end{array} $		21 26 29	29 36 43	mΩ
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 \text{ V},  I_D = 7.6 \text{ A}$		21		S
-	Characteristics		I			
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 20 V$ , $V_{GS} = 0 V$ ,		760		pF
Coss	Output Capacitance	f = 1.0  MHz		100		pF
Crss	Reverse Transfer Capacitance	_		60		pF
R <sub>G</sub>	Gate Resistance	f = 1.0 MHz		1.2		Ω
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 20 V, I_D = 1 A,$		9	18	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		5	10	ns
t <sub>d(off)</sub>	Turn–Off Delay Time			23	17	ns
t <sub>f</sub>	Turn–Off Fall Time			3	6	ns
Qg	Total Gate Charge	$V_{DS} = 20 V$ , $I_D = 7.6 A$ ,		7.7	11	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 5 V$		2.4		nC
Q <sub>gd</sub>	Gate–Drain Charge			2.8		nC
Drain-So	ource Diode Characteristics					
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = 2.1 A$ (Note 2)		0.76	1.2	V
t <sub>rr</sub>	Diode Reverse Recovery Time	$I_F = 7.6 \text{ A}, \qquad d_{iF}/d_t = 100 \text{ A}/\mu\text{s}$		17		nS
Q <sub>rr</sub>	Diode Reverse Recovery Charge	$1_{\rm F} = 7.0 \rm A$ , $u_{\rm F}/u_{\rm f} = 100 \rm A/\mu s$		7		nC







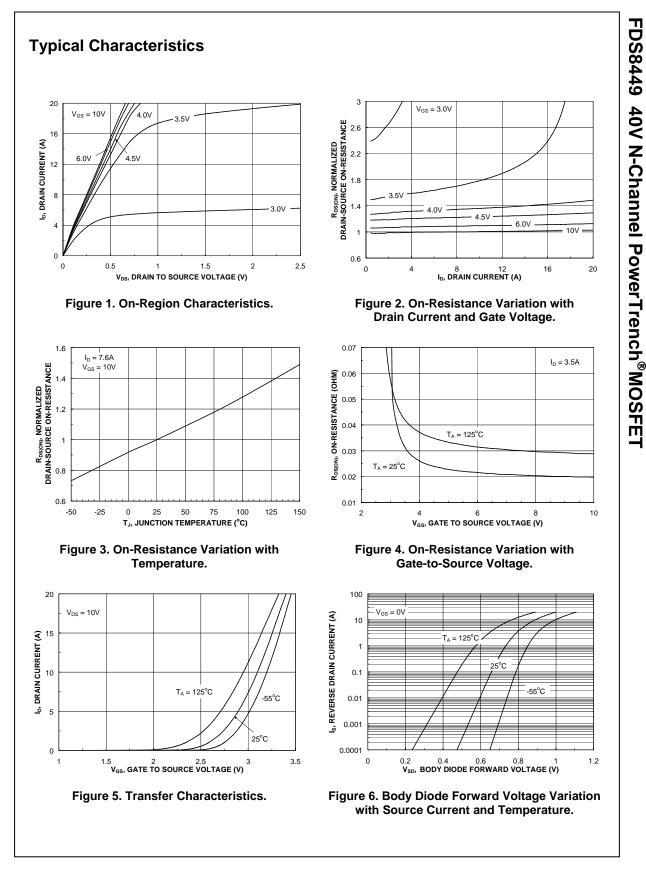
b) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

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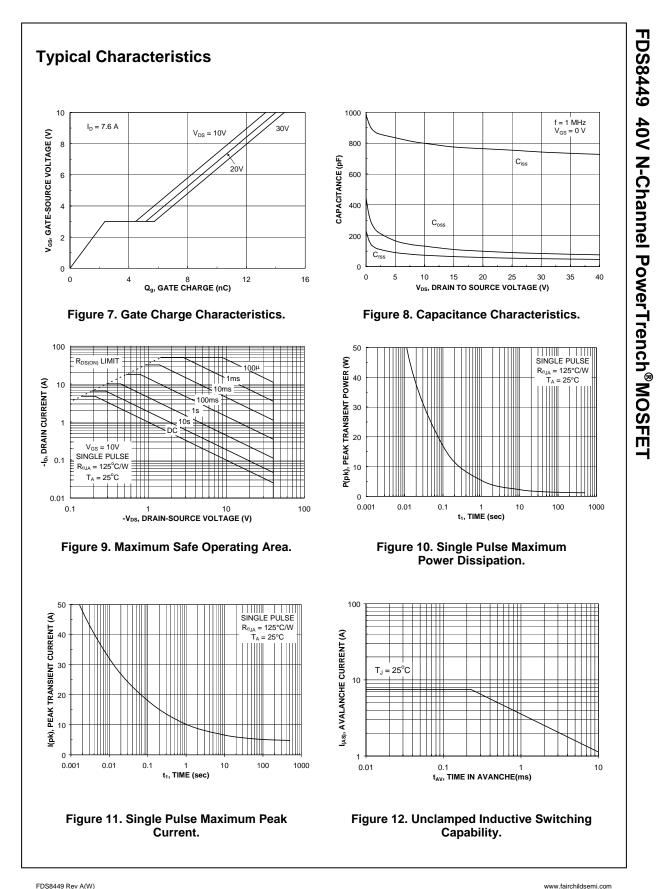
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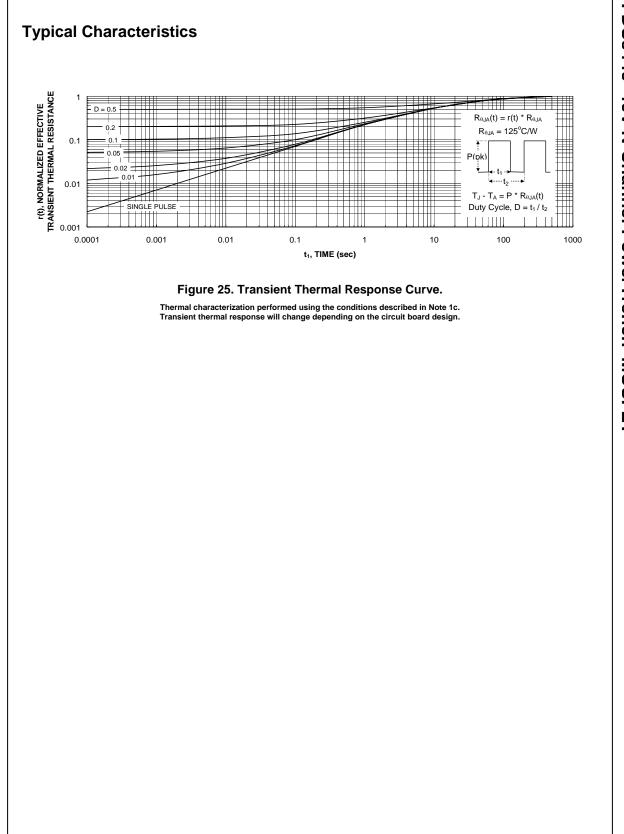
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